_				7/	
	L	Hits	Search Text	DB	Time stamp
	Number				
	1	0	(gate near electrode) and ( "0.1" near	USPAT;	2002/06/01
ا 👡			micrometer) and (patterning) and (shruken	US-PGPUB;	09:35
			or reduced) with (low near K near	EPO; JPO;	
			dieelctric ) with mask	DERWENT;	
ı			discipation , with man.	IBM TDB	İ
		0	/mate mean electrode and / "O 1" near	USPAT;	2002/06/01
	8	U	(gate near electrode) and ("0.1" near		09:35
			micrometer) and (patterning) and (	US-PGPUB;	09:35
- 1			shrunken or reduced) with (low near K	EPO; JPO;	
- 1			near dieelctric ) with mask	DERWENT;	
- 1				IBM_TDB	
- 1	15	0	(gate near electrode) and ( "0.1" near	USPAT;	2002/06/01
			micrometer) and (patterning) and (	US-PGPUB;	09:35
- 1			shrunken or reduced) with (low near K	EPO; JPO;	
ı			near dielectric ) with mask	DERWENT;	
			Tical dicicotife , with mask	IBM TDB	
	0.0	_	/t	USPAT;	2002/06/01
- {	22 -	0	1 (3	•	
- 1			( shrunken or reduced) with (low near K	US-PGPUB;	09:36
1			near dielectric ) with mask	EPO; JPO;	
				DERWENT;	
-				IBM_TDB	
	29	0	(gate near electrode) and (patterning) and	USPAT;	2002/06/01
- 1			(low near K near dielectric ) with mask	US-PGPUB;	09:36
			, , , , , , , , , , , , , , , , , , , ,	EPO; JPO;	
				DERWENT;	
-				IBM TDB	
ļ	2.5			_	2002/06/01
	36	10		USPAT;	2002/06/01
			near dielectric ) with mask	US-PGPUB;	09:37
-				EPO; JPO;	
				DERWENT;	
				IBM TDB	
- 1	50	0	(gate) and (patterning) and ( shrunken or	USPAT;	2002/06/01
ı	30		reduce\$2) and (low near K near dielectric	US-PGPUB;	09:38
ŀ					09.30
-			) with mask and ( "0.1" near micromeer)	EPO; JPO;	
- 1				DERWENT;	
- 1				IBM_TDB	
	57	0	1 (3 (F (F ), )	USPAT;	2002/06/01
			reduce\$2) and (low near K near dielectric	US-PGPUB;	09:38
			) with mask and ( "0.1" near micrometer)	EPO; JPO;	
- 1				DERWENT;	
				IBM TDB	
- 1	43	8	(gate) and (patterning) and ( shrunken or	USPAT;	2002/06/01
	13	0	reduce\$2) and (low near K near dielectric	US-PGPUB;	09:42
			) with mask	EPO; JPO;	~~
- 1			/ WICH MASK		,
				DERWENT;	
				IBM_TDB	0000 (0 5 (5 5
	64	0	( ) ( )	USPAT;	2002/06/01
- 1			reduce\$2)and (low near K near dielectric	US-PGPUB;	09:43
- 1			) with mask and ( fine near pattern)	EPO; JPO;	
-			•	DERWENT;	
				IBM TDB	
	71	0	(gate) and (patterning) and ( shrunken or	USPAT;	2002/06/01
	′ +	U			09:47
- 1			reduce\$2) and (low near K near dielectric	US-PGPUB;	09.47
			) with mask and ("100" near nanometer)	EPO; JPO;	
- 1				DERWENT;	
				IBM_TDB	
	78	0	(garat, and the control of the con	USPAT;	2002/06/01
			near dielectric ) with mask and ("100"	US-PGPUB;	09:48
- 1			near nanometer)	EPO; JPO;	
- 1			<b>,</b>	DERWENT;	
				IBM TDB	
	85	9	   (gate)and (patterning)and ("100" near	USPAT;	2002/06/01
	03	9		· ·	09:48
			nanometer) and (low near K near dielectric	US-PGPUB;	U 9:40
			)	EPO; JPO;	
				DERWENT;	
				IBM_TDB	

			<b>N</b> )	
92	5	(gate) and (patterning) and ("100" near	USPAT;	2002/06/01
		nanometer) and (low near K near dielectric	US-PGPUB;	09:51
		) and mask	EPO; JPO;	
1	1		DERWENT;	
	1		IBM TDB	
99	751849	(gate)withand ("100" near nanometer)and	USPAT;	2002/06/01
		(patterning) and (low near K near	US-PGPUB;	09:52
		dielectric ) and mask	EPO; JPO;	
		,	DERWENT;	
			IBM TDB	
106	0	(gate)with ("100" near nanometer)and	USPAT;	2002/06/01
200		(patterning) and (low near K near	US-PGPUB;	09:53
		dielectric ) and mask	EPO; JPO;	
1		The state of the s	DERWENT;	
			IBM TDB	
113	0	(gate) and (patterning) with ("100" near	USPAT;	2002/06/01
1113		nanometer) and (feature near size) and	US-PGPUB;	09:54
		(low near K near dielectric ) and mask	EPO; JPO;	05.01
		(low hear K hear dielectric ) and mask	DERWENT;	ł
			IBM TDB	
120	1	(gate) and (patterning) with ("100" near	USPAT;	2002/06/01
120	1	nanometer) and (feature) and (low near K	US-PGPUB;	10:22
	ļ	near dielectric ) and mask	EPO; JPO;	10.22
		Hear dielectic / and mask	DERWENT;	
			IBM TDB	
127	,	(gate) and (patterning) with ("100" near	USPAT;	2002/06/01
127	2	nanometer) and (feature)	US-PGPUB;	10:28
ŀ		Hallometer and (leature)	EPO; JPO;	10.20
		·	DERWENT;	
			IBM TDB	
134	7	"5648293"	USPAT;	2002/06/01
134	/	J040293	US-PGPUB;	10:25
			EPO; JPO;	10.23
			DERWENT;	
			IBM TDB	ļ
141	1 1	"6358856"	USPAT;	2002/06/01
141	1	000000	US-PGPUB;	10:29
			·	10.29
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	<u> </u>

	Туре	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	;	(gate near electrode) and ( "O.1" near micrometer) and (patterning) and (shruken or reduced) with (low near K near dieelctric ) with mask	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:35
2	BRS	L8	0	/	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:35
3	BRS	L15	0	:/	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:35
4	BRS	L22	0	(gate near electrode) and (patterning) and (shrunken	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01
5	BRS	L29	0	(gate near electrode)and (patterning)and (low near K near dielectric ) with mask		2002/06/01 09:36

	Туре	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L36	10	(gate)and (patterning)and (low near K near dielectric ) with mask	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:37
7	BRS	L50	0	/les man V man dialogtria	EPO;	2002/06/01 09:38
8	BRS	L57	0	(gate) and (patterning) and (shrunken or reduce\$2) and (low near K near dielectrice) with mask and ("0.1" near micrometer)	EPO;	2002/06/01 09:38
9	BRS	L43	8	(gate)and (patterning)and (shrunken or reduce\$2)and (low near K near dielectric) with mask	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:42
10	BRS	L64	0	(gate) and (patterning) and (shrunken or reduce\$2) and (low near K near dielectric) with mask and (fine near pattern)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:43

	Туре	L #	Hits	Search Text	DBs	Time Stamp
11	BRS	L71		(gate)and (patterning)and (	EPO;	
12	BRS	L78	0	(gate)and (patterning)and (low near K near dielectric ) with mask and ("100" near nanometer)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:48
13	BRS	L85	9	(gate)and (patterning)and ("100" near nanometer)and (low near K near dielectric )		2002/06/01 09:48
14	BRS	L92	5	(gate)and (patterning)and ("100" near nanometer)and (low near K near dielectric ) and mask	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 09:51
15	BRS	L99	!	(gate)withand ("100" near nanometer)and (patterning)and (low near K near dielectric ) and mask	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	

	Туре	L #	Hits	Search Text	DBs	Time Stamp
16	BRS	L106	<u> </u>	(gate)with ("100" near nanometer)and (patterning)and (low near K		2002/06/01 09:53
17	BRS	L113	0	(gate) and (patterning) with	EPO;	2002/06/01 09:54
18	BRS	L120	1	(gate)and (patterning)with ("100" near nanometer)and (feature) and (low near K near dielectric ) and mask	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 10:22
19	BRS	L127	2	(gate) and (patterning) with ("100" near nanometer) and (feature)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 10:28
20	BRS	L134	7	"5648293"	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 10:25

	Туре	L #	Hits	Search Text	DBs	Time Stamp
21	BRS	L141	1	"6358856"	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/06/01 10:29